



61

AF 2812 -

Attorney's Docket No.: 10559-587001
Intel Docket No.: P12768

?

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Been-Yih Jin et al.
Serial No. : 10/081,992
Filed : February 21, 2002
Title : NON-SILICON SEMICONDUCTOR AND HIGH-K GATE DIELECTRIC
METAL OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTORS

Art Unit : 2812
Examiner : Ron E. Pompey
Assignee : Intel Corporation

MAIL STOP AF

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

REPLY


In reply to the action mailed May 21, 2003, please amend the application as indicated on the following pages. Applicant asks that all claims be allowed in view of the amendment to the claims and remarks contained on the following sheets, a total of 7 pages.

No fee is believed to be due for this Reply; however, if any fees are due, please charge them to Deposit Account No. 06-1050.

Respectfully submitted,

Date: July 24, 2003

Attorneys for Intel
Fish & Richardson P.C.
225 Franklin Street
Boston, MA 02110-2804
Telephone: (617) 542-5070
Facsimile: (617) 542-8906
20680142.doc


Paul A. Pysher
Reg. No. 40,780

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Date of Deposit

Signature

Typed or Printed Name of Person Signing Certificate

RECEIVED
JUL 25 2003
TECHNICAL CENTER 2800